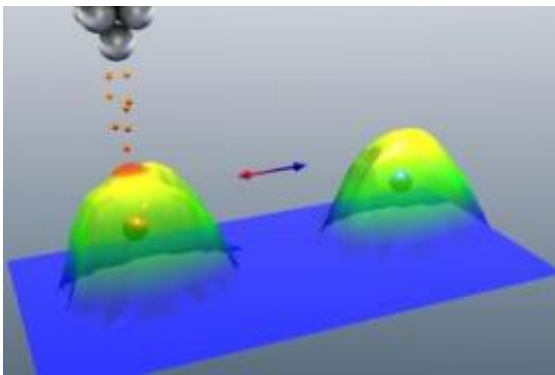


# Researchers switch magnetic state and electric resistance of a single molecule on and off

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Using a scanning tunneling microscope tip, defined electricity pulses were applied to the molecule, which switches between different magnetic states. (photo: CFN/KIT)

One bit of digital information stored on a hard disk currently consists of about 3 million magnetic atoms. Researchers from Germany and Japan have now developed a magnetic memory with one bit per molecule. By an electric pulse, the metal-organic molecule can be switched reliably between a conductive, magnetic state and a low-conductive, non-magnetic state. This novel correlation for molecules is now reported in the *Nature Communications* journal.

“The superparamagnetic effect prevents smaller bit sizes from being

reached in a hard disk," explains Toshio Miyamachi, first author of the study and researcher at the Center for Functional Nanostructures (CFN) of Karlsruhe Institute of Technology (KIT). This super-paramagnetic effect implies that magnetic memory crystals are increasingly susceptible to thermal switching with decreasing size. Consequently, information may soon be lost.

"We chose another approach and placed a single magnetic iron atom in the center of an [organic molecule](#) consisting of 51 atoms. The organic shell protects the information stored in the central atom." Apart from the ultimate density of one bit per molecule, this type of memory based on so-called spin crossover molecules also has the advantage of the writing process being reliable and purely electric.

"Using a scanning tunneling microscope, we applied defined electricity pulses to the nanometer-sized molecule," adds Wulf Wulfhekel, head of the research group at KIT's Physikalisches Institut. "This reproducibly changes not only the magnetic state of the iron, but also the electric properties of the molecule." Hence, the two magnetic configurations lead to varying conductances, such that the magnetic state of the molecule can be determined easily by a simple resistance measurement.

The present study reports the fundamentals and shows the principle feasibility and advantages of memories consisting of spin crossover [molecules](#). "These memristive and spintronic properties combined in a molecule will open up a new field of research," the researchers are convinced. Memristors are memories that store information in the form of resistance variations. Spintronics uses the magnetic spin of individual particles for information processing.

**More information:** T. Miyamachi, M. Gruber, V. Davesne, M. Bowen, S. Boukari, L. Joly, F. Scheurer, G. Rogez, T.K. Yamada, P. Ohresser, E. Beaure-paire, W. Wulfhekel, Robust spin crossover and

memristance across a single molecule. *Nat. Commun.* , doi:  
10.1038/ncomms1940

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